NSN 5961-01-317-9373

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-317-9373 **Inclosure Material:** Ceramic **Overall Length:** 1.8 millimeters **Overall Height:** 12.0 millimeters **Overall Width:** 12.0 millimeters **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 70.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 290.0 milliwatts small-signal input power, common-collector absolute **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter and 250.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No